

Vishay Siliconix

COMPLIANT

P-Channel 60 V (D-S) 175 °C MOSFET

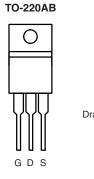
PRODUC	T SUMMARY	Y			
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A) ^c			
- 60	0.0093 at V _{GS} = - 10 V	- 90			
- 60	0.0118 at V _{GS} = - 4.5 V	- 90			

FEATURES

- TrenchFET[®] Power MOSFET
- Compliant to RoHS Directive 2002/95/EC



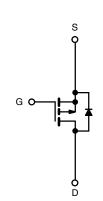
• DC/DC Primary Switch



Drain connected to Tab

Top View

Ordering Information: SUP90P06-09L-E3 (Lead (Pb)-free)



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T $_{\rm C}$ =	25 °C, unless othe	rwise noted)			
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	- 60	v	
Gate-Source Voltage		V _{GS}	± 20		
Continuous Drain Current /T 175 °C'C	T _C = 25 °C	1-	- 90		
Continuous Drain Current $(T_J = 175 \ ^{\circ}C)^{c}$	T _C = 125 °C		- 67	A	
Pulsed Drain Current		I _{DM}	- 200	A	
Avalanche Current	L = 0.1 mH	I _{AS}	- 65		
Single Pulse Avalanche Energy ^a	L = 0.1 mH	E _{AS}	211	mJ	
Power Dissipation	T _C = 25 °C	P _D	250 ^b	w	
	T _A = 25 °C		2.4	vv	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 175	°C	

Symbol	Limit	Unit
R _{thJA}	62	°C/W
R _{thJC}	0.6	0/10
	R _{thJA}	R _{thJA} 62

Notes:

a. Duty cycle \leq 1 %.

b. See SOA curve for voltage derating.

c. Limited by package.

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V, I_D = -250 \mu A$	- 60		V		
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = -250 \ \mu A$			- 3	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
Zero Gate Voltage Drain Current		$V_{DS} = -60 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			- 1		
	I _{DSS}	V_{DS} = - 60 V, V_{GS} = 0 V, T_{J} = 125 °C			- 50) μΑ	
		V_{DS} = - 60 V, V_{GS} = 0 V, T_{J} = 175 °C			- 250		
On-State Drain Current ^a	I _{D(on)}	V _{DS} = - 5 V, V _{GS} = - 10 V	- 120			Α	
		V _{GS} = - 10 V, I _D = - 30 A		0.0074	0.0093		
		V_{GS} = - 10 V, I _D = - 30 A, T _J = 125 °C			0.0150	Ω	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V_{GS} = - 10 V, I _D = - 30 A, T _J = 175 °C			0.0190		
		V _{GS} = - 4.5 V, I _D = - 20 A		0.0094	0.0118		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 15 V, I _D = - 30 A	20			S	
Dynamic ^b							
Input Capacitance	C _{iss}			9200		pF	
Output Capacitance	C _{oss}	V _{GS} = 0 V, V _{DS} = - 25 V, f = 1 MHz		975			
Reverse Transfer Capacitance	C _{rss}			760			
Total Gate Charge ^c	Qg			160	240		
Gate-Source Charge ^c	Q _{gs}	$V_{DS} = -30 \text{ V}, V_{GS} = -10 \text{ V}, I_{D} = -90 \text{ A}$		40		nC	
Gate-Drain Charge ^c	Q _{gd}			36			
Gate Resistance	R _g	f = 1.0 MHz		3		Ω	
Turn-On Delay Time ^c	t _{d(on)}			20	30		
Rise Time ^c	t _r	V_{DD} = - 30 V, R_{L} = 0.33 Ω		190	285		
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong$ - 90 A, V_{GEN} = - 10 V, R_g = 2.5 Ω		140	210	ns	
Fall Time ^c	t _f			300	450	1	
Source-Drain Diode Ratings and Cha	aracteristics	(T _C = 25 °C) ^b			<u> </u>		
Continuous Current	I _S			1	- 90		
Pulsed Current	I _{SM}				- 200	A	
Forward Voltage ^a	V _{SD}	I _F = - 50 A, V _{GS} = 0 V		- 1.0	- 1.5	V	
Reverse Recovery Time	t _{rr}			60	90	ns	
Peak Reverse Recovery Current	I _{RM(REC)}	I _F = - 50 A, dl/dt = 100 A/μs		- 3	- 4.5	А	
Reverse Recovery Charge	Q _{rr}	1		0.09	0.2	μC	

Notes:

a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

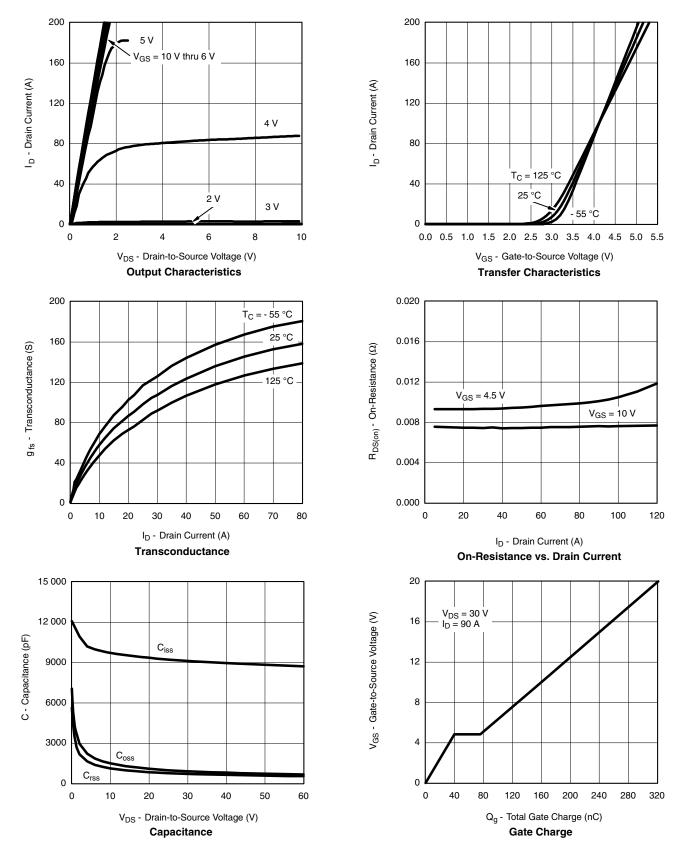
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



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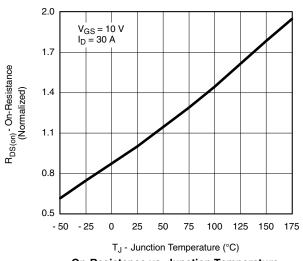


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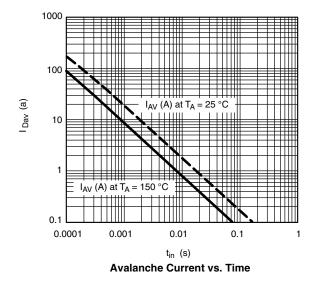


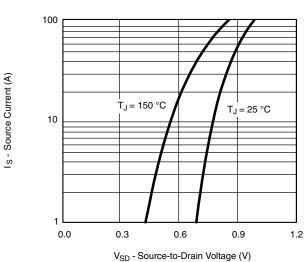
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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

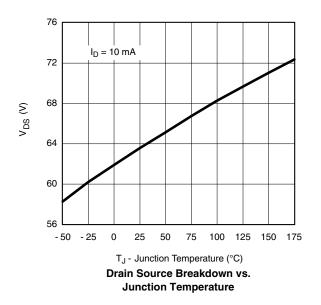


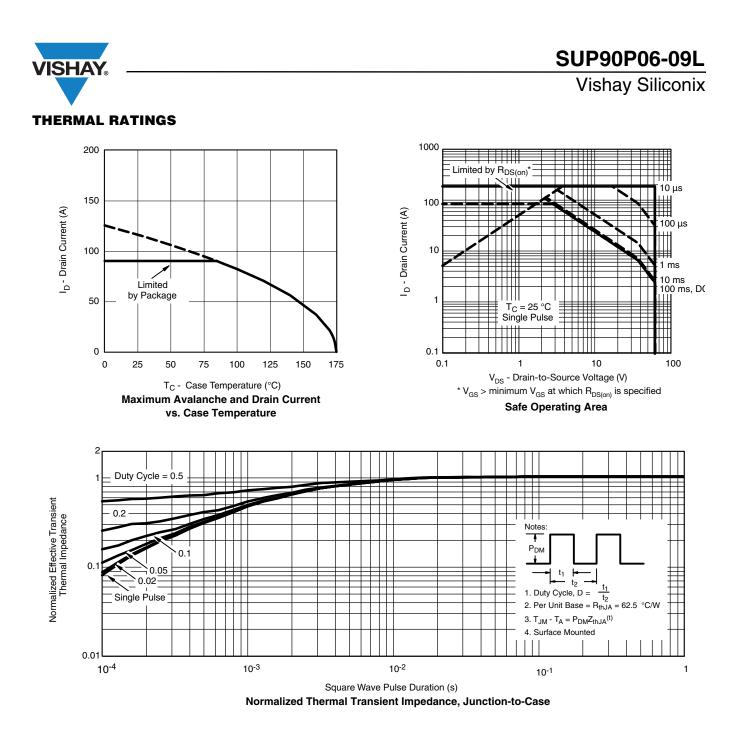






Source-Drain Diode Forward Voltage



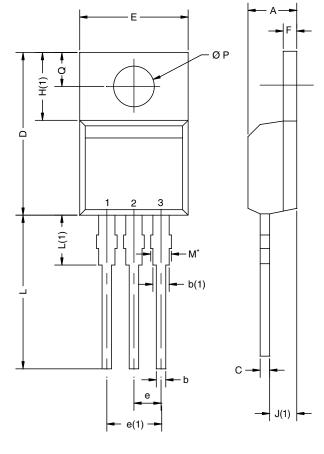


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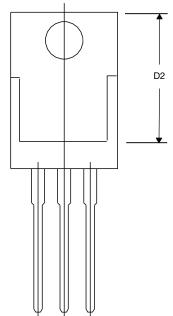
TO-220AB



	MILLIN	IETERS	INC	HES
DIM.	MIN.	MAX.	MIN.	MAX.
А	4.25	4.65	0.167	0.183
b	0.69	1.01	0.027	0.040
b(1)	1.20	1.73	0.047	0.068
С	0.36	0.61	0.014	0.024
D	14.85	15.49	0.585	0.610
D2	12.19	12.70	0.480	0.500
Е	10.04	10.51	0.395	0.414
е	2.41	2.67	0.095	0.105
e(1)	4.88	5.28	0.192	0.208
F	1.14	1.40	0.045	0.055
H(1)	6.09	6.48	0.240	0.255
J(1)	2.41	2.92	0.095	0.115
L	13.35	14.02	0.526	0.552
L(1)	3.32	3.82	0.131	0.150
ØΡ	3.54	3.94	0.139	0.155
Q	2.60	3.00	0.102	0.118
ECN: T14- DWG: 547	0413-Rev. P, 1	16-Jun-14		

Note

 * M = 1.32 mm to 1.62 mm (dimension including protrusion) Heatsink hole for HVM



Revison: 16-Jun-14

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